TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT process)

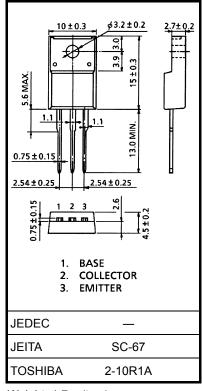
# 2SC5353

Switching Regulator and High Voltage Switching Applications High-Speed DC-DC Converter Applications

- Excellent switching times:  $t_r$  = 0.7  $\mu s$  (max),  $t_f$  = 0.5  $\mu s$  (max)
- High collectors breakdown voltage:  $V_{CEO} = 800 \text{ V}$

#### Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	900	V	
Collector-emitter voltage		V <sub>CEO</sub>	800	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	Ι <sub>C</sub>	3	А	
	Pulse	I <sub>CP</sub>	5	~	
Base current		Ι <sub>Β</sub>	1	А	
Collector power dissipation	Ta = 25°C	Pc	2.0	W	
	Tc = 25°C	FC	25		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

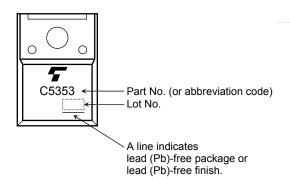
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

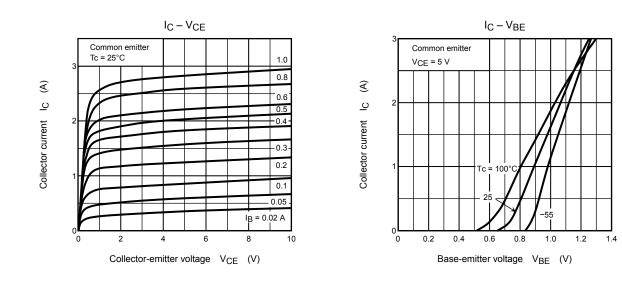
Electrical Characteristics (Tc = 25°C)

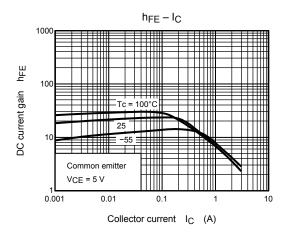
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 720 V, I <sub>E</sub> = 0	_	_	100	μA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	_	10	μA
Collector-base breakdown voltage		V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0	900	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	800	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	10	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.15 A	15	_	_	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 1.2 A, I <sub>B</sub> = 0.24 A	_	_	1.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 1.2 A, I <sub>B</sub> = 0.24 A		_	1.3	V
Switching time	Rise time	tr	Output $I_{C} \downarrow \otimes 0$ $I_{B1} = 0.24 \text{ A}, I_{B2} = -0.48 \text{ A},$ duty cycle $\leq 1\%$	_	_	0.7	
	Storage time	t <sub>stg</sub>		_	_	4.0	μs
	Fall time	t <sub>f</sub>		_	_	0.5	

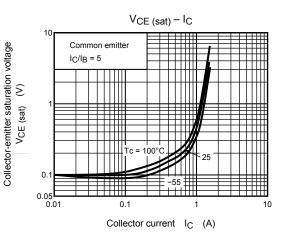
## Marking

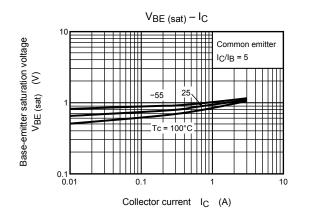


# **TOSHIBA**

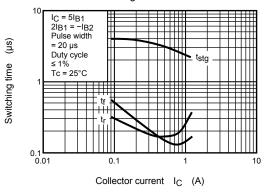


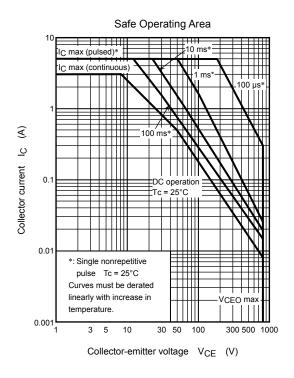


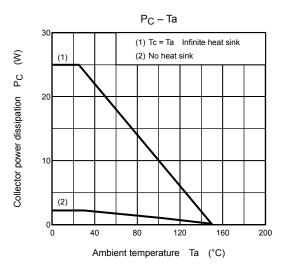




Switching Characteristics







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